# Single Inverter with Open Drain Outputs

The NL17SZ06 is a high performance single inverter with open drain outputs operating from a 1.65 to 5.5 V supply.

The Output stage is open drain with Over Voltage Tolerance. This allows the NL17SZ06 to be used to interface 5.0 V circuits to circuits of any voltage between 0 and +7.0 V.

#### **Features**

- Tiny SOT-353 and SOT-553 Packages
- Extremely High Speed:  $t_{PD}$  2.5 ns (typical) at  $V_{CC} = 5.0 \text{ V}$
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation, CMOS Compatible
- • Over Voltage Tolerant Inputs  $V_{IN}$  may be Between 0 and 7.0 V for  $V_{CC}$  Between 0.5 and 5.4 V
- TTL Compatible Interface Capability with 5.0 V TTL Logic with  $V_{CC}$  = 2.7 V to 3.6 V
- LVCMOS Compatible
- 24 mA Output Sink Capability, Pullup may be between 0 and 7.0 V
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Chip Complexity: FET = 20
- Pb-Free Packages are Available

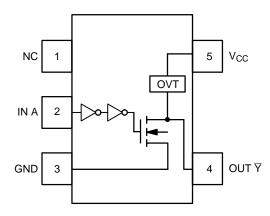


Figure 1. Pinout (Top View)



Figure 2. Logic Symbol



# ON Semiconductor®

http://onsemi.com



#### SOT-353/SC70-5/SC-88A DF SUFFIX CASE 419A

MARKING DIAGRAMS

d = Date Code





SOT-553 XV5 SUFFIX CASE 463B

LF = Device MarkingD = One Digit Date Code

#### **PIN ASSIGNMENT**

Pin	Function
1	NC
2	IN A
3	GND
4	OUT ₹
5	V <sub>CC</sub>

# **FUNCTION TABLE**

A Input	▼ Output		
L	Z		
Н	L		

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### **MAXIMUM RATINGS**

Symbol		Characteristics	Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
VI	DC Input Voltage		$-0.5 \le V_1 \le +7.0$	V
Vo	DC Output Voltage	Output in Z or LOW State (Note 1)	$-0.5 \le V_O \le 7.0$	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>I</sub> < GND	-50	mA
I <sub>OK</sub>	DC Output Diode Current	V <sub>O</sub> < GND	-50	mA
Io	DC Output Sink Current		±50	mA
I <sub>CC</sub>	DC Supply Current Per Supp	oly Pin	±100	mA
I <sub>GND</sub>	DC Ground Current Per Gro	±100	mA	
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
P <sub>D</sub>	Power Dissipation in Still Air	SOT-353 SOT-553	186 135	mW
$\theta_{JA}$	Thermal Resistance	SOT-353 SOT-553	350 496	°C/W
$T_L$	Lead Temperature, 1 mm fro	m Case for 10 Seconds	260	°C
TJ	Junction Temperature Under	Bias	+150	°C
I <sub>Latch-Up</sub>	Latchup Performance	Above V <sub>CC</sub> and Below GND at 85°C (Note 5)	±500	mA
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
ESD	ESD Classification	Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	Class IC Class A N/A	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- I<sub>O</sub> absolute maximum rating must be observed.
   Tested to EIA/JESD22-A114-A, rated to EIA/JESD22-A114-B.
   Tested to EIA/JESD22-A115-A, rated to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA/JESD78.

# **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit	
V <sub>CC</sub>	Supply Voltage	Operating Data Retention Only	1.65 1.5	5.5 5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	(Z or LOW State)	0	5.5	V
T <sub>A</sub>	Operating Free-Air Temperature		-40	+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0 0	20 10 5	ns/V

# DC ELECTRICAL CHARACTERISTICS

			v <sub>cc</sub>	Т	A = 25°	С	$-40^{\circ}C \le T_A \le 85^{\circ}C$		
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input Voltage		1.65 to 1.95 2.3 to 5.5	0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>			0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>		V
V <sub>IL</sub>	Low-Level Input Voltage		1.65 to 1.95 2.3 to 5.5			0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>		0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>	V
I <sub>LKG</sub>	Z-State Output Leakage Current	$V_{IN} = V_{IL}$ $V_{OUT} = V_{CC}$ or GND	2.3 to 5.5			±5.0		±10.0	μΑ
V <sub>OL</sub>	Low-Level Output	I <sub>OL</sub> = 100 μA	1.65 to 5.5		0.0	0.1		0.1	V
	Voltage V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 4 mA	1.65		0.08	0.24		0.24	
	" " "	I <sub>OL</sub> = 8 mA	2.3		0.22	0.3		0.3	
		I <sub>OL</sub> = 12 mA	2.7		0.22	0.4		0.4	
		I <sub>OL</sub> = 16 mA	3.0		0.28	0.4		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.38	0.55		0.55	
		I <sub>OL</sub> = 32 mA	4.5		0.42	0.55		0.55	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> or V <sub>OUT</sub> = V <sub>CC</sub> or GND	0 to 5.5			± 0.1		±1.0	μΑ
I <sub>OFF</sub>	Power Off–Output Leakage Current	V <sub>OUT</sub> = 5.5 V	0			1.0		10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			1.0		10	μΑ

# AC ELECTRICAL CHARACTERISTICS $t_R=t_F=2.5~\text{ns};~C_L=50~\text{pF};~R_L=500~\Omega$

			$T_{A} = 25^{\circ}C \qquad \qquad -40^{\circ}C \le T_{A} \le 85^{\circ}C$		T <sub>A</sub> = 25°C		T <sub>A</sub> ≤ 85°C		
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit
t <sub>PZL</sub>	Propagation Delay	$R_{L=} R_{1} = 500 \Omega, C_{L} = 50 pF$	1.65	0.8	5.3	11.6	0.8	12.0	ns
	(Figure 3 and 4)		2.5 ± 0.2	0.8	3.0	3.6	0.8	4.1	
			$3.3 \pm 0.3$	0.8	2.4	3.2	0.8	3.7	
			$5.0 \pm 0.5$	0.5	2.4	3.0	0.5	3.5	
t <sub>PLZ</sub>	Propagation Delay	$R_{L=} R_{1} = 500 \Omega, C_{L} = 50 pF$	1.65	0.8	5.3	11.6	0.8	12.0	ns
	(Figure 3 and 4)		2.5 ± 0.2	0.8	2.5	3.6	0.8	4.1	
			$3.3 \pm 0.3$	0.8	2.1	3.2	0.8	3.7	
			$5.0 \pm 0.5$	0.5	1.2	3.0	0.5	3.5	

# **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Parameter Condition		Unit
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	>2.5	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 5.5 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	4.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	10 MHz, $V_{CC}$ = 5.5 V, $V_{I}$ = 0 V or $V_{CC}$	4.0	pF

<sup>6.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

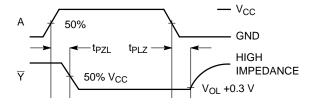
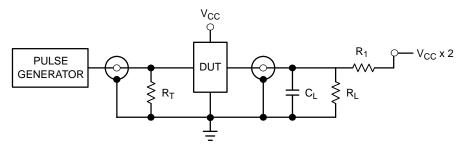


Figure 3. Switching Waveforms



 $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

Figure 4. Test Circuit

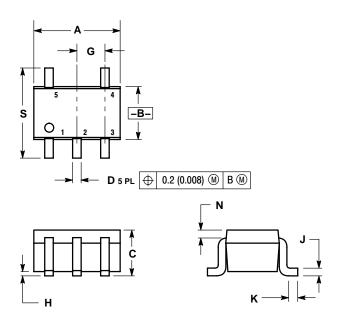
# **DEVICE ORDERING INFORMATION**

	Device Nomenclature								
Device Order Number	Logic Circuit Indicator	No. of Gates per Package	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape & Reel Suffix	Package Type	Tape and Reel Size <sup>†</sup>
NL17SZ06DFT2	NL	1	7	SZ	06	DF	T2	SOT-353/ SC70-5/ SC-88A	178 mm (7") 3000 Unit
NL17SZ06DFT2G	NL	1	7	SZ	06	DF	T2	SOT-353/ SC70-5/ SC-88A (Pb-Free)	178 mm (7") 3000 Unit
NL17SZ06XV5T2	NL	1	7	SZ	06	XV5	T2	SOT-553*	178 mm (7") 4000 Unit

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*All Devices in Package SOT553 are Inherently Pb–Free.

# **PACKAGE DIMENSIONS**

#### SOT-353 **DF SUFFIX** 5-LEAD PACKAGE CASE 419A-02 ISSUE G



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

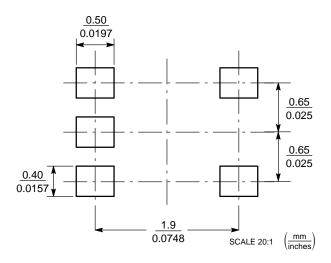
  2. CONTROLLING DIMENSION: INCH.

  3. 419A-01 OBSOLETE. NEW STANDARD 419A-02.

  4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	INC	HES	MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
С	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026	BSC	0.65 BSC		
Н		0.004		0.10	
J	0.004	0.010	0.10	0.25	
K	0.004	0.012	0.10	0.30	
N	0.008	REF	0.20	REF	
S	0.079	0.087	2 00	2 20	

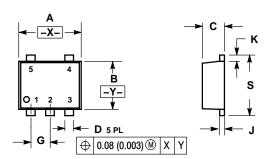
# **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

SOT-553 XV5 SUFFIX 5-LEAD PACKAGE CASE 463B-01 **ISSUE A** 



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETERS 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.50	1.70	0.059	0.067
В	1.10	1.30	0.043	0.051
С	0.50	0.60	0.020	0.024
D	0.17	0.27	0.007	0.011
G	0.50	BSC	0.020	BSC
J	0.08	0.18	0.003	0.007
K	0.10	0.30	0.004	0.012
S	1.50	1.70	0.059	0.067

PIN 1. BASE 1 EMITTER 1/2 3 BASE 2

OF BASE MATERIAL

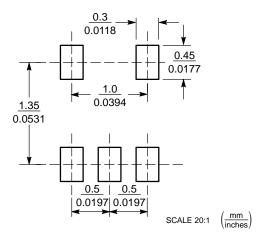
COLLECTOR 2 5. COLLECTOR 1

STYLE 2: PIN 1. CATHODE

2. ANODE 3. CATHODE

CATHODE

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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